Ordering number: EN3581

PNP/NPN Epitaxial Planar Silicon Transistors



## 2SA1787/2SC4650

# **High-Definition CRT Display Video Output Applications**

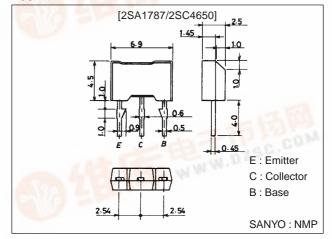
#### **Features**

- · High breakdown voltage : V<sub>CEO</sub>≥200V.
- · Small reverse transfer capacitance and excellent high frequency characteristic:
- $C_{re}=1.2pF (NPN), 1.7pF (PNP).$
- · Adoption of FBET processes.

### **Package Dimensions**

unit:mm

2064



(): 2SA1786

## **Specifications**

#### Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CBO</sub>		(-)200	V
Collector-to-Emitter Voltage	V <sub>CEO</sub>		(-)200	V
Emitter-to-Base Voltage	V <sub>EBO</sub>		(-)5	V
Collector Current	IC	Total T	(-)100	mA
Colletor Current (Pulse)	ICP	- A TOP	(-)200	mA
Collector Dissipation	PC	AND LATE VEG	1.0	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

## Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions		Ratings		
			min	typ	max	Unit
Collector Cutoff Current	ICBO	V <sub>CB</sub> =(-)150V, I <sub>E</sub> =0			(–)0.1	μA
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =(-)4V, I <sub>C</sub> =0			(-)0.1	μΑ
DC Current Gain	h <sub>FE</sub>	V <sub>CE</sub> =(-)10V, I <sub>C</sub> =(-)10mA	60		320	
Gain-Bandwidth Product	f <sub>T</sub>	V <sub>CE</sub> =(-)30V, I <sub>C</sub> =(-)10mA		150		MHz
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =(-)30V, f=1MHz		(2.6)	20.	pF
		/ A-X \	Was and	1.7		pF
Reverse Transfer Capacitance	C <sub>re</sub>	V <sub>CB</sub> =(-)30V, f=1MHz		(1.7)		pF
				1.2		pF
Collector-to-Emitter Saturation Voltage	VCE(sat)	I <sub>C</sub> =(-)20mA, I <sub>B</sub> =(-)2mA			(-)0.6	V
Base-to-Emitter Saturation Voltage	V <sub>BE</sub> (sat)	I <sub>C</sub> =(-)20mA, I <sub>B</sub> =(-)2mA			(-)1.0	V

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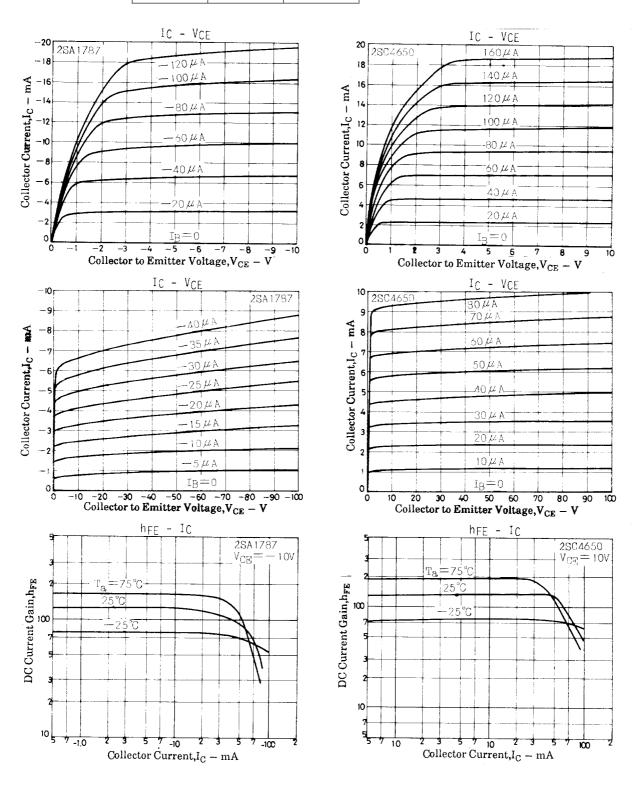
SANYO Electric Co.,Ltd. Semiconductor Bussiness Headquaters

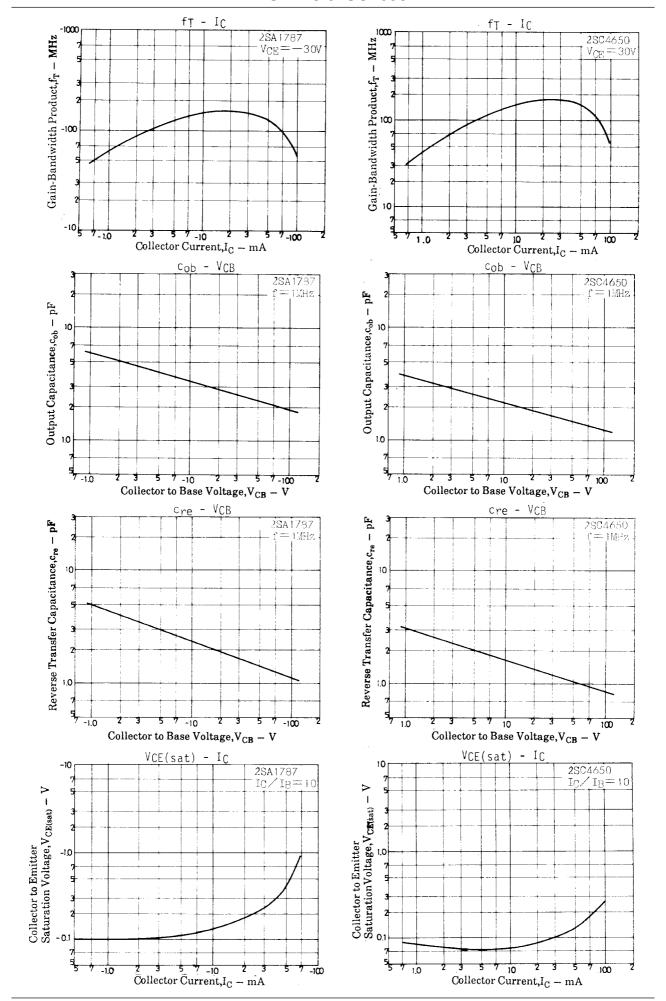
#### 2SA1787/2SC4650

Parameter	Symbol	rmbol Conditions	Ratings			Unit
Farameter Symbol	Symbol		min	typ	max	Offic
Collector-to-Base Breakdown Voltage	V(BR)CBO	I <sub>C</sub> =(-)10μA, I <sub>E</sub> =0	(–)200			V
Collector-to-Emitter Breakdown Voltage	V <sub>(BR)</sub> CEO	I <sub>C</sub> =(-)1mA, R <sub>BE</sub> =∞	(–)200			V
Emitter-to-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =(-)10μA, I <sub>C</sub> =0	(–)5			V

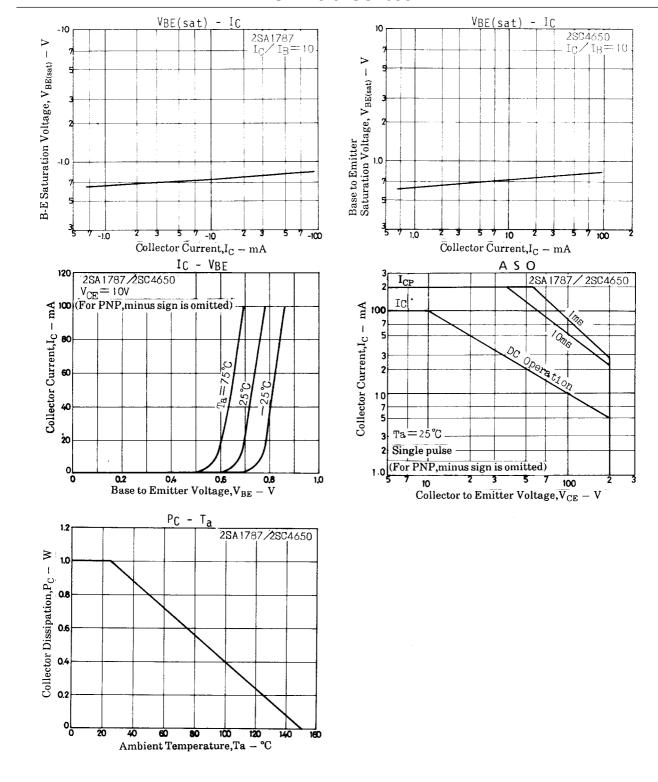
\* : The 2SA1787/2SC4650 are classified by 10mA  $h_{FE}$  as follows :

60 D 120 100 E 200 160 F
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## 2SA1787/2SC4650



#### 2SA1787/2SC4650

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